
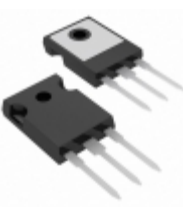
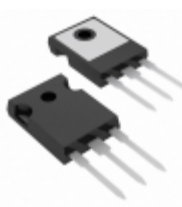

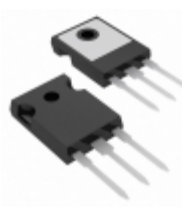
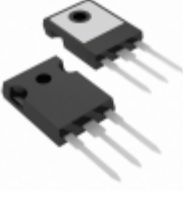
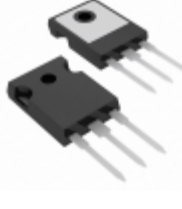
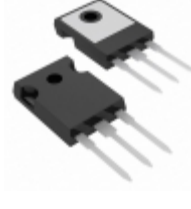
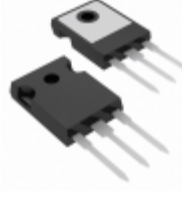
	<h2 style="color: red;">SIHG16N50C-E3</h2>
	<p>Hersteller-Teilenummer: SIHG16N50C-E3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 500V 16A TO-247AC</p> <p>Datenblätter:  SIHG16N50C-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 5490 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIHG16N50C-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 500V 16A TO-247AC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	5490 pcs Stock
Hersteller Standard Vorlaufzeit	11 Weeks
detaillierte Beschreibung	N-Channel 500V 16A (Tc) 250W (Tc) Through Hole
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-247-3
Supplier Device-Gehäuse	TO-247AC
Verlustleistung (max)	250W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	16A (Tc)
Rds On (Max) @ Id, Vgs	380 mOhm @ 8A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	68nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1900pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

SIHG16N50C-E3 ist neu im Original, Suche SIHG16N50C-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIHG16N50C-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SIHG16N50C-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIHG17N60D-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 600V 17A TO247AC</p>	 <p>SIHG15N60E-GE3 Vishay / Siliconix MOSFET N-CH 600V 15A TO247AC</p>	 <p>SIHG17N60D Vishay Precision Group SIHG17N60D VISHAY</p>	 <p>SIHG14N50D-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 500V 14A TO-247AC</p>
 <p>SIHG17N60D-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 600V 17A TO247AC</p>	 <p>SIHG17N60D-GE3 Vishay / Siliconix MOSFET N-CH 600V 17A TO247AC</p>	 <p>SIHG17N60D-E3 Vishay / Siliconix MOSFET N-CH 600V 17A TO247AC</p>	 <p>SIHG15N60E-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 600V 15A TO247AC</p>

heiße Teile

Mehr

⊛ SIHFR1N60ATL-E3	↔ SIHFR210	⇒ SIHFR210TR	D SIHFR214	↔ SIHFR220
↳ SIHFR220T	⊛ SIHFR224	D SIHFR320-E3	⇒ SIHFR420	↔ SIHFR420A
⊛ SIHFR430A	↳ SIHFR9010	⊛ SIHFR9012	↔ SIHFR9014	↔ SIHFR9020T
D SIHFR9024	⊛ SIHFR9110	↳ SIHFR9120	⊛ SIHFR9120T	↔ SIHFR9220
⇒ SIHFRC20	↔ SIHFRC20TL-E3	⊛ SIHFS11N50A	↳ SIHFS9N60A	↔ SIHFSL11N50A
↔ SIHG16N50C-E3	⇒ SIHG17N60D	D SIHG20N50C	⊛ SIHG22N60S-E3	↳ SIHG30N60E
⊛ SIHG33N60E	D SIHG47N60E-E3	⇒ SIHG47N60E-E3	↔ SIHG47N60E-GE3	↔ SIHG47N60E-GE3
↳ SIHG47N60S-E3	⊛ SIHG70N60EFEF-GE3	↔ SIHG73N60E-GE3	⇒ SIHG73N60E-GE3	↔ SIHP10N40D
⊛ SIHP12N50C-E3	↳ SIHP12N50C-E3	⊛ SIHP12N60E-E3	D SIHP12N60E-E3	↔ SIHP12N60E-GE3
↔ SIHP12N60E-GE3	⊛ SIHP12N65E	↳ SIHP14N50D	⊛ SIHP15N60E-E3	↔ SIHP15N60E-E3

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